

Welcome to **E-XFL.COM**

Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	858
Number of Logic Elements/Cells	6864
Total RAM Bits	245760
Number of I/O	281
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	324-VFBGA
Supplier Device Package	324-CSFBGA (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo3l-6900e-6mg324i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



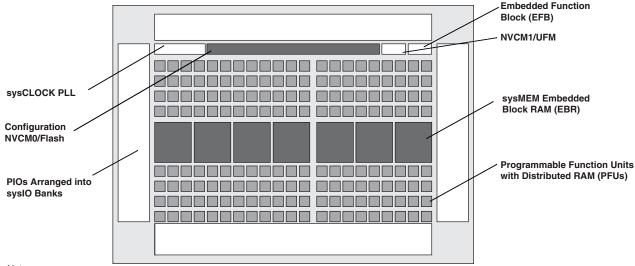
MachXO3 Family Data Sheet Architecture

February 2017 Advance Data Sheet DS1047

Architecture Overview

The MachXO3L/LF family architecture contains an array of logic blocks surrounded by Programmable I/O (PIO). All logic density devices in this family have sysCLOCK[™] PLLs and blocks of sysMEM Embedded Block RAM (EBRs). Figure 2-1 and Figure 2-2 show the block diagrams of the various family members.

Figure 2-1. Top View of the MachXO3L/LF-1300 Device



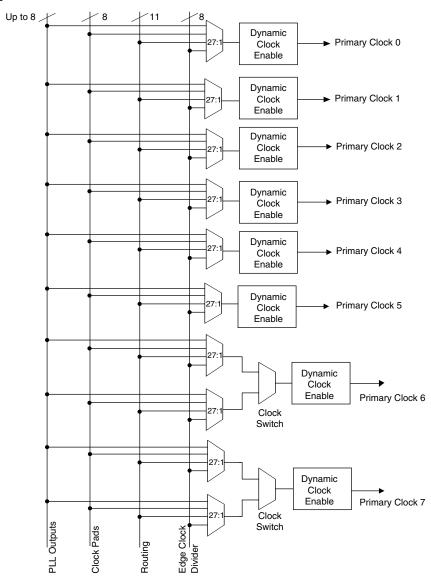
Notes:

- MachXO3L/LF-640 is similar to MachXO3L/LF-1300. MachXO3L/LF-640 has a lower LUT count.
- MachXO3L devices have NVCM, MachXO3LF devices have Flash.

www.latticesemi.com 2-1 DS1047 Introduction 0.8



Figure 2-5. Primary Clocks for MachXO3L/LF Devices



Eight secondary high fanout nets are generated from eight 8:1 muxes as shown in Figure 2-6. One of the eight inputs to the secondary high fanout net input mux comes from dual function clock pins and the remaining seven come from internal routing. The maximum frequency for the secondary clock network is shown in MachXO3L/LF External Switching Characteristics table.



Table 2-5. sysMEM Block Configurations

Memory Mode	Configurations
Single Port	8,192 x 1 4,096 x 2 2,048 x 4 1,024 x 9
True Dual Port	8,192 x 1 4,096 x 2 2,048 x 4 1,024 x 9
Pseudo Dual Port	8,192 x 1 4,096 x 2 2,048 x 4 1,024 x 9 512 x 18
FIFO	8,192 x 1 4,096 x 2 2,048 x 4 1,024 x 9 512 x 18

Bus Size Matching

All of the multi-port memory modes support different widths on each of the ports. The RAM bits are mapped LSB word 0 to MSB word 0, LSB word 1 to MSB word 1, and so on. Although the word size and number of words for each port varies, this mapping scheme applies to each port.

RAM Initialization and ROM Operation

If desired, the contents of the RAM can be pre-loaded during device configuration. EBR initialization data can be loaded from the NVCM or Configuration Flash.

MachXO3LF EBR initialization data can also be loaded from the UFM. To maximize the number of UFM bits, initialize the EBRs used in your design to an all-zero pattern. Initializing to an all-zero pattern does not use up UFM bits. MachXO3LF devices have been designed such that multiple EBRs share the same initialization memory space if they are initialized to the same pattern.

By preloading the RAM block during the chip configuration cycle and disabling the write controls, the sysMEM block can also be utilized as a ROM.

Memory Cascading

Larger and deeper blocks of RAM can be created using EBR sysMEM Blocks. Typically, the Lattice design tools cascade memory transparently, based on specific design inputs.

Single, Dual, Pseudo-Dual Port and FIFO Modes

Figure 2-8 shows the five basic memory configurations and their input/output names. In all the sysMEM RAM modes, the input data and addresses for the ports are registered at the input of the memory array. The output data of the memory is optionally registered at the memory array output.

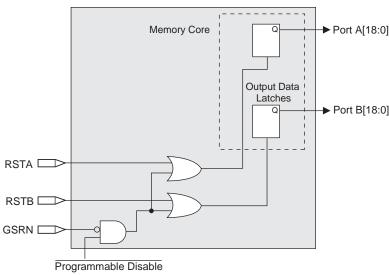


state. The RPRST signal is used to reset the read pointer. The purpose of this reset is to retransmit the data that is in the FIFO. In these applications it is important to keep careful track of when a packet is written into or read from the FIFO.

Memory Core Reset

The memory core contains data output latches for ports A and B. These are simple latches that can be reset synchronously or asynchronously. RSTA and RSTB are local signals, which reset the output latches associated with port A and port B respectively. The Global Reset (GSRN) signal resets both ports. The output data latches and associated resets for both ports are as shown in Figure 2-9.

Figure 2-9. Memory Core Reset

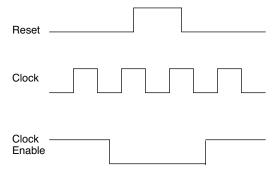


For further information on the sysMEM EBR block, please refer to TN1290, Memory Usage Guide for MachXO3 Devices.

EBR Asynchronous Reset

EBR asynchronous reset or GSR (if used) can only be applied if all clock enables are low for a clock cycle before the reset is applied and released a clock cycle after the reset is released, as shown in Figure 2-10. The GSR input to the EBR is always asynchronous.

Figure 2-10. EBR Asynchronous Reset (Including GSR) Timing Diagram



If all clock enables remain enabled, the EBR asynchronous reset or GSR may only be applied and released after the EBR read and write clock inputs are in a steady state condition for a minimum of 1/f_{MAX} (EBR clock). The reset release must adhere to the EBR synchronous reset setup time before the next active read or write clock edge.



Table 2-11 shows the I/O standards (together with their supply and reference voltages) supported by the MachXO3L/LF devices. For further information on utilizing the sysIO buffer to support a variety of standards please see TN1280, MachXO3 sysIO Usage Guide.

Table 2-11. Supported Input Standards

		V	CCIO (Ty	p.)	
Input Standard	3.3 V	2.5 V	1.8 V	1.5 V	1.2 V
Single-Ended Interfaces					
LVTTL	Yes				
LVCMOS33	Yes				
LVCMOS25		Yes			
LVCMOS18			Yes		
LVCMOS15				Yes	
LVCMOS12					Yes
PCI	Yes				
Differential Interfaces					
LVDS	Yes	Yes			
BLVDS, MLVDS, LVPECL, RSDS	Yes	Yes			
MIPI ¹	Yes	Yes			
LVTTLD	Yes				
LVCMOS33D	Yes				
LVCMOS25D		Yes			
LVCMOS18D			Yes		

^{1.} These interfaces can be emulated with external resistors in all devices.



Figure 2-15. MachXO3L/LF-1300 in 256 Ball Packages, MachXO3L/LF-2100, MachXO3L/LF-4300, MachXO3L/LF-6900 and MachXO3L/LF-9400 Banks

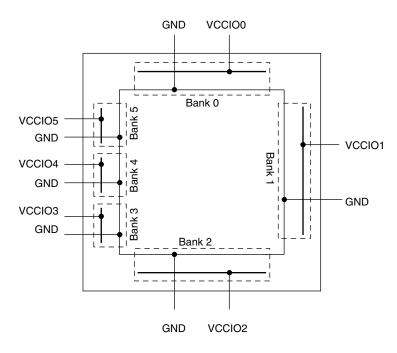
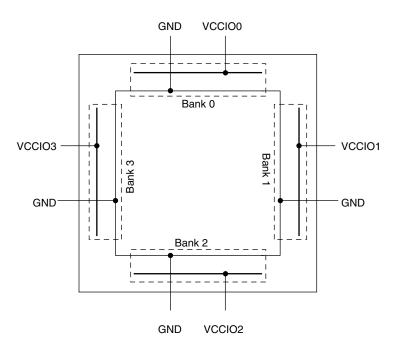


Figure 2-16. MachXO3L/LF-640 and MachXO3L/LF-1300 Banks

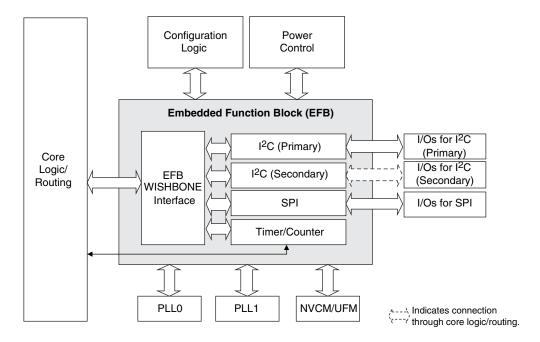




Embedded Hardened IP Functions

All MachXO3L/LF devices provide embedded hardened functions such as SPI, I²C and Timer/Counter. MachXO3LF devices also provide User Flash Memory (UFM). These embedded blocks interface through the WISHBONE interface with routing as shown in Figure 2-17.

Figure 2-17. Embedded Function Block Interface



Hardened I²C IP Core

Every MachXO3L/LF device contains two I²C IP cores. These are the primary and secondary I²C IP cores. Either of the two cores can be configured either as an I²C master or as an I²C slave. The only difference between the two IP cores is that the primary core has pre-assigned I/O pins whereas users can assign I/O pins for the secondary core.

When the IP core is configured as a master it will be able to control other devices on the I²C bus through the interface. When the core is configured as the slave, the device will be able to provide I/O expansion to an I²C Master. The I²C cores support the following functionality:

- · Master and Slave operation
- 7-bit and 10-bit addressing
- · Multi-master arbitration support
- Up to 400 kHz data transfer speed
- General call support
- Interface to custom logic through 8-bit WISHBONE interface



There are some limitations on the use of the hardened user SPI. These are defined in the following technical notes:

- TN1087, Minimizing System Interruption During Configuration Using TransFR Technology (Appendix B)
- TN1293, Using Hardened Control Functions in MachXO3 Devices

Figure 2-19. SPI Core Block Diagram

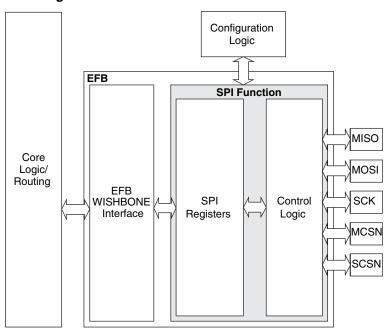


Table 2-15 describes the signals interfacing with the SPI cores.

Table 2-15. SPI Core Signal Description

Signal Name	I/O	Master/Slave	Description
spi_csn[0]	0	Master	SPI master chip-select output
spi_csn[17]	0	Master	Additional SPI chip-select outputs (total up to eight slaves)
spi_scsn	I	Slave	SPI slave chip-select input
spi_irq	0	Master/Slave	Interrupt request
spi_clk	I/O	Master/Slave	SPI clock. Output in master mode. Input in slave mode.
spi_miso	I/O	Master/Slave	SPI data. Input in master mode. Output in slave mode.
spi_mosi	I/O	Master/Slave	SPI data. Output in master mode. Input in slave mode.
sn	I	Slave	Configuration Slave Chip Select (active low), dedicated for selecting the Configuration Logic.
cfg_stdby	0	Master/Slave	Stand-by signal – To be connected only to the power module of the MachXO3L/LF device. The signal is enabled only if the "Wakeup Enable" feature has been set within the EFB GUI, SPI Tab.
cfg_wake	0	Master/Slave	Wake-up signal – To be connected only to the power module of the MachXO3L/LF device. The signal is enabled only if the "Wakeup Enable" feature has been set within the EFB GUI, SPI Tab.



MachXO3 Family Data Sheet DC and Switching Characteristics

February 2017 Advance Data Sheet DS1047

Absolute Maximum Ratings^{1, 2, 3}

	MachXO3L/LF E (1.2 V)	MachXO3L/LF C (2.5 V/3.3 V)
Supply Voltage V _{CC}	–0.5 V to 1.32 V	–0.5 V to 3.75 V
Output Supply Voltage V _{CCIO}	–0.5 V to 3.75 V	–0.5 V to 3.75 V
I/O Tri-state Voltage Applied ^{4, 5}	–0.5 V to 3.75 V	–0.5 V to 3.75 V
Dedicated Input Voltage Applied ⁴	–0.5 V to 3.75 V	0.5 V to 3.75 V
Storage Temperature (Ambient)	–55 °C to 125 °C	–55 °C to 125 °C
Junction Temperature (T _J)	–40 °C to 125 °C	–40 °C to 125 °C

^{1.} Stress above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

- 2. Compliance with the Lattice Thermal Management document is required.
- 3. All voltages referenced to GND.
- 4. Overshoot and undershoot of -2 V to $(V_{IHMAX} + 2)$ volts is permitted for a duration of <20 ns.
- 5. The dual function I²C pins SCL and SDA are limited to -0.25 V to 3.75 V or to -0.3 V with a duration of <20 ns.

Recommended Operating Conditions¹

Symbol	Parameter		Max.	Units
V 1	Core Supply Voltage for 1.2 V Devices	1.14	1.26	V
V _{CC} ¹	Core Supply Voltage for 2.5 V/3.3 V Devices	2.375	3.465	V
V _{CCIO} ^{1, 2, 3}	I/O Driver Supply Voltage	1.14	3.465	V
t _{JCOM}	Junction Temperature Commercial Operation	0	85	°C
t _{JIND}	Junction Temperature Industrial Operation	-40	100	°C

Like power supplies must be tied together. For example, if V_{CCIO} and V_{CC} are both the same voltage, they must also be the same supply.

Power Supply Ramp Rates¹

Symbol	Parameter	Min.	Тур.	Max.	Units
t _{RAMP}	Power supply ramp rates for all power supplies.	0.01	1	100	V/ms

^{1.} Assumes monotonic ramp rates.

^{2.} See recommended voltages by I/O standard in subsequent table.

^{3.} V_{CCIO} pins of unused I/O banks should be connected to the V_{CC} power supply on boards.



Programming and Erase Supply Current – C/E Devices^{1, 2, 3, 4}

Symbol	Parameter	Device	Typ.⁴	Units
I _{CC}	Core Power Supply	LCMXO3L/LF-1300C 256 Ball Package	22.1	mA
		LCMXO3L/LF-2100C	22.1	mA
		LCMXO3L/LF-2100C 324 Ball Package	26.8	mA
		LCMXO3L/LF-4300C	26.8	mA
		LCMXO3L/LF-4300C 400 Ball Package	33.2	mA
		LCMXO3L/LF-6900C	33.2	mA
		LCMXO3L/LF-9400C	39.6	mA
		LCMXO3L/LF-640E	17.7	mA
		LCMXO3L/LF-1300E	17.7	mA
		LCMXO3L/LF-1300E 256 Ball Package	18.3	mA
		LCMXO3L/LF-2100E	18.3	mA
		LCMXO3L/LF-2100E 324 Ball Package	20.4	mA
		LCMXO3L/LF-4300E	20.4	mA
		LCMXO3L/LF-6900E	23.9	mA
		LCMXO3L/LF-9400E	28.5	mA
I _{CCIO}	Bank Power Supply ⁵ VCCIO = 2.5 V	All devices	0	mA

^{1.} For further information on supply current, please refer to TN1289, Power Estimation and Management for MachXO3 Devices.

^{2.} Assumes all inputs are held at $\ensuremath{V_{\text{CCIO}}}$ or GND and all outputs are tri-stated.

^{3.} Typical user pattern.

^{4.} JTAG programming is at 25 MHz.

^{5.} $T_J = 25$ °C, power supplies at nominal voltage.

^{6.} Per bank. $V_{CCIO} = 2.5 \text{ V}$. Does not include pull-up/pull-down.



MIPI D-PHY Emulation

MachXO3L/LF devices can support MIPI D-PHY unidirectional HS (High Speed) and bidirectional LP (Low Power) inputs and outputs via emulation. In conjunction with external resistors High Speed IOs use the LVDS25E buffer and Low Power IOs use the LVCMOS buffers. The scheme shown in Figure 3-4 is one possible solution for MIPI D-PHY Receiver implementation. The scheme shown in Figure 3-5 is one possible solution for MIPI D-PHY Transmitter implementation.

Figure 3-4. MIPI D-PHY Input Using External Resistors

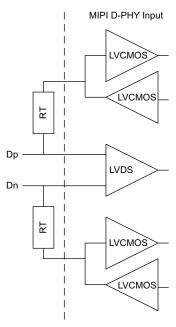


Table 3-4. MIPI DC Conditions¹

	Description	Min.	Тур.	Max.	Units
Receiver		l		l	
External Termi	nation				
RT	1% external resistor with VCCIO=2.5 V	_	50	_	Ohms
	1% external resistor with VCCIO=3.3 V	_	50		Ohms
High Speed	•		•		•
VCCIO	VCCIO of the Bank with LVDS Emulated input buffer	_	2.5	_	V
	VCCIO of the Bank with LVDS Emulated input buffer	_	3.3	_	V
VCMRX	Common-mode voltage HS receive mode	150	200	250	mV
VIDTH	Differential input high threshold	_	_	100	mV
VIDTL	Differential input low threshold	-100	_	_	mV
VIHHS	Single-ended input high voltage	_	_	300	mV
VILHS	Single-ended input low voltage	100	_	_	mV
ZID	Differential input impedance	80	100	120	Ohms



Typical Building Block Function Performance – C/E Devices¹

Pin-to-Pin Performance (LVCMOS25 12 mA Drive)

Function	–6 Timing	Units
Basic Functions		
16-bit decoder	8.9	ns
4:1 MUX	7.5	ns
16:1 MUX	8.3	ns

Register-to-Register Performance

–6 Timing	Units
	•
412	MHz
297	MHz
324	MHz
161	MHz
	•
183	MHz
	<u> </u>
500	MHz
	412 297 324 161

^{1.} The above timing numbers are generated using the Diamond design tool. Exact performance may vary with device and tool version. The tool uses internal parameters that have been characterized but are not tested on every device. Commercial timing numbers are shown at 85 °C and 1.14 V. Other operating conditions, including industrial, can be extracted from the Diamond software.

Derating Logic Timing

Logic timing provided in the following sections of the data sheet and the Lattice design tools are worst case numbers in the operating range. Actual delays may be much faster. Lattice design tools can provide logic timing numbers at a particular temperature and voltage.



			_	6	_	5	
Parameter	Description	Device	Min.	Max.	Min.	Max.	Units
General I/O	Pin Parameters (Using Edge Clock without	t PLL)	1				
		MachXO3L/LF-1300	_	7.53	_	7.76	ns
		MachXO3L/LF-2100	_	7.53	_	7.76	ns
t _{COE}	Clock to Output - PIO Output Register	MachXO3L/LF-4300	_	7.45	_	7.68	ns
		MachXO3L/LF-6900		7.53	_	7.76	ns
		MachXO3L/LF-9400	_	8.93	_	9.35	ns
		MachXO3L/LF-1300	-0.19		-0.19		ns
		MachXO3L/LF-2100	-0.19	_	-0.19	_	ns
t _{SUE}	Clock to Data Setup - PIO Input Register	MachXO3L/LF-4300	-0.16	_	-0.16	_	ns
		MachXO3L/LF-6900	-0.19	_	-0.19	_	ns
		MachXO3L/LF-9400	-0.20		-0.20		ns
		MachXO3L/LF-1300	1.97	_	2.24	_	ns
		MachXO3L/LF-2100	1.97	_	2.24	_	ns
t _{HE}	Clock to Data Hold - PIO Input Register	MachXO3L/LF-4300	1.89	_	2.16	_	ns
		MachXO3L/LF-6900	1.97	_	2.24	_	ns
		MachXO3L/LF-9400	1.98	_	2.25	_	ns
	Clock to Data Setup - PIO Input Register with Data Input Delay	MachXO3L/LF-1300	1.56	_	1.69	_	ns
		MachXO3L/LF-2100	1.56	_	1.69	_	ns
t _{SU_DELE}		MachXO3L/LF-4300	1.74		1.88	_	ns
		MachXO3L/LF-6900	1.66	_	1.81	_	ns
		MachXO3L/LF-9400	1.71	_	1.85	_	ns
		MachXO3L/LF-1300	-0.23		-0.23	_	ns
		MachXO3L/LF-2100	-0.23	_	-0.23		ns
t _{H_DELE}	Clock to Data Hold - PIO Input Register with Input Data Delay	MachXO3L/LF-4300	-0.34		-0.34		ns
	Input Bata Belay	MachXO3L/LF-6900	-0.29	_	-0.29	_	ns
		MachXO3L/LF-9400	-0.30		-0.30		ns
General I/O	Pin Parameters (Using Primary Clock with	PLL)					
		MachXO3L/LF-1300		5.98	_	6.01	ns
		MachXO3L/LF-2100	_	5.98	_	6.01	ns
t _{COPLL}	Clock to Output - PIO Output Register	MachXO3L/LF-4300	_	5.99	_	6.02	ns
		MachXO3L/LF-6900	_	6.02	_	6.06	ns
		MachXO3L/LF-9400	_	5.55	_	6.13	ns
		MachXO3L/LF-1300	0.36		0.36		ns
		MachXO3L/LF-2100	0.36		0.36		ns
t _{SUPLL}	Clock to Data Setup - PIO Input Register	MachXO3L/LF-4300	0.35	_	0.35	_	ns
		MachXO3L/LF-6900	0.34	_	0.34		ns
		MachXO3L/LF-9400	0.33	_	0.33		ns
		MachXO3L/LF-1300	0.42	1	0.49	l	ns
		MachXO3L/LF-2100	0.42		0.49		ns
t _{HPLL}	Clock to Data Hold - PIO Input Register	MachXO3L/LF-4300	0.43		0.50		ns
		MachXO3L/LF-6900	0.46	l	0.54	l	ns
		MachXO3L/LF-9400	0.47		0.55		ns



MachXO3 Family Data Sheet Pinout Information

February 2017 Advance Data Sheet DS1047

Signal Descriptions

Signal Name	I/O	Descriptions
General Purpose		
		[Edge] indicates the edge of the device on which the pad is located. Valid edge designations are L (Left), B (Bottom), R (Right), T (Top).
		[Row/Column Number] indicates the PFU row or the column of the device on which the PIO Group exists. When Edge is T (Top) or (Bottom), only need to specify Row Number. When Edge is L (Left) or R (Right), only need to specify Column Number.
		[A/B/C/D] indicates the PIO within the group to which the pad is connected.
P[Edge] [Row/Column Number]_[A/B/C/D]	I/O	Some of these user-programmable pins are shared with special function pins. When not used as special function pins, these pins can be programmed as I/Os for user logic.
		During configuration of the user-programmable I/Os, the user has an option to tri-state the I/Os and enable an internal pull-up, pull-down or buskeeper resistor. This option also applies to unused pins (or those not bonded to a package pin). The default during configuration is for user-programmable I/Os to be tri-stated with an internal pull-down resistor enabled. When the device is erased, I/Os will be tri-stated with an internal pull-down resistor enabled. Some pins, such as PROGRAMN and JTAG pins, default to tri-stated I/Os with pull-up resistors enabled when the device is erased.
NC	_	No connect.
GND	_	GND – Ground. Dedicated pins. It is recommended that all GNDs are tied together.
VCC	_	V_{CC} – The power supply pins for core logic. Dedicated pins. It is recommended that all VCCs are tied to the same supply.
VCCIOx	_	VCCIO – The power supply pins for I/O Bank x. Dedicated pins. It is recommended that all VCCIOs located in the same bank are tied to the same supply.
PLL and Clock Function	ons (Us	ed as user-programmable I/O pins when not used for PLL or clock pins)
[LOC]_GPLL[T, C]_IN	_	Reference Clock (PLL) input pads: [LOC] indicates location. Valid designations are L (Left PLL) and R (Right PLL). T = true and C = complement.
[LOC]_GPLL[T, C]_FB	_	Optional Feedback (PLL) input pads: [LOC] indicates location. Valid designations are L (Left PLL) and R (Right PLL). T = true and C = complement.
PCLK [n]_[2:0]	_	Primary Clock pads. One to three clock pads per side.
Test and Programming	g (Dual f	unction pins used for test access port and during sysCONFIG™)
TMS	I	Test Mode Select input pin, used to control the 1149.1 state machine.
TCK	ı	Test Clock input pin, used to clock the 1149.1 state machine.
TDI	I	Test Data input pin, used to load data into the device using an 1149.1 state machine.
TDO	0	Output pin – Test Data output pin used to shift data out of the device using 1149.1.
		Optionally controls behavior of TDI, TDO, TMS, TCK. If the device is configured to use the JTAG pins (TDI, TDO, TMS, TCK) as general purpose I/O, then:
JTAGENB	1	If JTAGENB is low: TDI, TDO, TMS and TCK can function a general purpose I/O.
		If JTAGENB is high: TDI, TDO, TMS and TCK function as JTAG pins.
		For more details, refer to TN1279, MachXO3 Programming and Configuration Usage Guide.



Signal Descriptions (Cont.)

Signal Name	I/O	Descriptions						
Configuration (Dual fu	Configuration (Dual function pins used during sysCONFIG)							
PROGRAMN	I	Initiates configuration sequence when asserted low. This pin always has an active pull-up.						
INITN	I/O	Open Drain pin. Indicates the FPGA is ready to be configured. During configuration, a pull-up is enabled.						
DONE	I/O	Open Drain pin. Indicates that the configuration sequence is complete, and the start-up sequence is in progress.						
MCLK/CCLK	I/O	Input Configuration Clock for configuring an FPGA in Slave SPI mode. Output Configuration Clock for configuring an FPGA in SPI and SPIm configuration modes.						
SN	I	Slave SPI active low chip select input.						
CSSPIN	I/O	Master SPI active low chip select output.						
SI/SPISI	I/O	Slave SPI serial data input and master SPI serial data output.						
SO/SPISO	I/O	Slave SPI serial data output and master SPI serial data input.						
SCL	I/O	Slave I ² C clock input and master I ² C clock output.						
SDA	I/O	Slave I ² C data input and master I ² C data output.						



Pin Information Summary

	MachXO3L/LF -640		MachXO3	L/LF-1300	
	CSFBGA121	WLCSP36	CSFBGA121	CSFBGA256	CABGA256
General Purpose IO per Bank					
Bank 0	24	15	24	50	50
Bank 1	26	0	26	52	52
Bank 2	26	9	26	52	52
Bank 3	24	4	24	16	16
Bank 4	0	0	0	16	16
Bank 5	0	0	0	20	20
Total General Purpose Single Ended IO	100	28	100	206	206
Differential IO per Bank	•				
Bank 0	12	8	12	25	25
Bank 1	13	0	13	26	26
Bank 2	13	4	13	26	26
Bank 3	11	2	11	8	8
Bank 4	0	0	0	8	8
Bank 5	0	0	0	10	10
Total General Purpose Differential IO	49	14	49	103	103
Dual Function IO	33	25	33	33	33
Number 7:1 or 8:1 Gearboxes	•				
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	7	3	7	14	14
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	7	2	7	14	14
High-speed Differential Outputs	•		•	1	
Bank 0	7	3	7	14	14
VCCIO Pins	•		•	1	
Bank 0	1	1	1	4	4
Bank 1	1	0	1	3	4
Bank 2	1	1	1	4	4
Bank 3	3	1	3	2	1
Bank 4	0	0	0	2	2
Bank 5	0	0	0	2	1
vcc	4	2	4	8	8
GND	10	2	10	24	24
NC	0	0	0	0	1
Reserved for Configuration	1	1	1	1	1
Total Count of Bonded Pins	121	36	121	256	256



	MachXO3L/LF-2100						
	WLCSP49	CSFBGA121	CSFBGA256	CSFBGA324	CABGA256	CABGA324	
General Purpose IO per Bank			I.	l	l	I	
Bank 0	19	24	50	71	50	71	
Bank 1	0	26	52	62	52	68	
Bank 2	13	26	52	72	52	72	
Bank 3	0	7	16	22	16	24	
Bank 4	0	7	16	14	16	16	
Bank 5	6	10	20	27	20	28	
Total General Purpose Single Ended IO	38	100	206	268	206	279	
Differential IO per Bank	<u>, </u>		ı	l .	ı	l .	
Bank 0	10	12	25	36	25	36	
Bank 1	0	13	26	30	26	34	
Bank 2	6	13	26	36	26	36	
Bank 3	0	3	8	10	8	12	
Bank 4	0	3	8	6	8	8	
Bank 5	3	5	10	13	10	14	
Total General Purpose Differential IO	19	49	103	131	103	140	
Dual Function IO	25	33	33	37	33	37	
Number 7:1 or 8:1 Gearboxes	•	•					
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	5	7	14	18	14	18	
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	6	13	14	18	14	18	
High-speed Differential Outputs	•	•					
Bank 0	5	7	14	18	14	18	
VCCIO Pins	•	•					
Bank 0	2	1	4	4	4	4	
Bank 1	0	1	3	4	4	4	
Bank 2	1	1	4	4	4	4	
Bank 3	0	1	2	2	1	2	
Bank 4	0	1	2	2	2	2	
Bank 5	1	1	2	2	1	2	
vcc	2	4	8	8	8	10	
GND	4	10	24	16	24	16	
NC	0	0	0	13	1	0	
Reserved for Configuration	1	1	1	1	1	1	
Total Count of Bonded Pins	49	121	256	324	256	324	



			Ма	chXO3L/LF	-4300		
	WLCSP81	CSFBGA121	CSFBGA256	CSFBGA324	CABGA256	CABGA324	CABGA400
General Purpose IO per Bank		I .				I	I
Bank 0	29	24	50	71	50	71	83
Bank 1	0	26	52	62	52	68	84
Bank 2	20	26	52	72	52	72	84
Bank 3	7	7	16	22	16	24	28
Bank 4	0	7	16	14	16	16	24
Bank 5	7	10	20	27	20	28	32
Total General Purpose Single Ended IO	63	100	206	268	206	279	335
Differential IO per Bank		•				•	•
Bank 0	15	12	25	36	25	36	42
Bank 1	0	13	26	30	26	34	42
Bank 2	10	13	26	36	26	36	42
Bank 3	3	3	8	10	8	12	14
Bank 4	0	3	8	6	8	8	12
Bank 5	3	5	10	13	10	14	16
Total General Purpose Differential IO	31	49	103	131	103	140	168
Dual Function IO	25	37	37	37	37	37	37
Number 7:1 or 8:1 Gearboxes		•				•	•
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	10	7	18	18	18	18	21
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	10	13	18	18	18	18	21
High-speed Differential Outputs		•				•	•
Bank 0	10	7	18	18	18	18	21
VCCIO Pins							
Bank 0	3	1	4	4	4	4	5
Bank 1	0	1	3	4	4	4	5
Bank 2	2	1	4	4	4	4	5
Bank 3	1	1	2	2	1	2	2
Bank 4	0	1	2	2	2	2	2
Bank 5	1	1	2	2	1	2	2
vcc	4	4	8	8	8	10	10
GND	6	10	24	16	24	16	33
NC	0	0	0	13	1	0	0
Reserved for Configuration	1	1	1	1	1	1	1
Total Count of Bonded Pins	81	121	256	324	256	324	400



	MachXO3L/LF-9400C					
	CSFBGA256	CABGA256	CABGA400	CABGA484		
General Purpose IO per Bank				l .		
Bank 0	50	50	83	95		
Bank 1	52	52	84	96		
Bank 2	52	52	84	96		
Bank 3	16	16	28	36		
Bank 4	16	16	24	24		
Bank 5	20	20	32	36		
Total General Purpose Single Ended IO	206	206	335	383		
Differential IO per Bank		•	•	•		
Bank 0	25	25	42	48		
Bank 1	26	26	42	48		
Bank 2	26	26	42	48		
Bank 3	8	8	14	18		
Bank 4	8	8	12	12		
Bank 5	10	10	16	18		
Total General Purpose Differential IO	103	103	168	192		
Dual Function IO	37	37	37	45		
Number 7:1 or 8:1 Gearboxes				•		
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	20	20	22	24		
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	20	20	22	24		
High-speed Differential Outputs		•	•	•		
Bank 0	20	20	21	24		
VCCIO Pins		l	l	l		
Bank 0	4	4	5	9		
Bank 1	3	4	5	9		
Bank 2	4	4	5	9		
Bank 3	2	1	2	3		
Bank 4	2	2	2	3		
Bank 5	2	1	2	3		
vcc	8	8	10	12		
GND	24	24	33	52		
NC	0	1	0	0		
Reserved for Configuration	1	1	1	1		
Total Count of Bonded Pins	256	256	400	484		



MachXO3LF Ultra Low Power Commercial and Industrial Grade Devices, Halogen Free (RoHS) Packaging

Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3LF-640E-5MG121C	640	1.2 V	5	Halogen-Free csfBGA	121	COM
LCMXO3LF-640E-6MG121C	640	1.2 V	6	Halogen-Free csfBGA	121	COM
LCMXO3LF-640E-5MG121I	640	1.2 V	5	Halogen-Free csfBGA	121	IND
LCMXO3LF-640E-6MG121I	640	1.2 V	6	Halogen-Free csfBGA	121	IND

Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3LF-1300E-5UWG36CTR	1300	1.2 V	5	Halogen-Free WLCSP	36	COM
LCMXO3LF-1300E-5UWG36CTR50	1300	1.2 V	5	Halogen-Free WLCSP	36	COM
LCMXO3LF-1300E-5UWG36CTR1K	1300	1.2 V	5	Halogen-Free WLCSP	36	COM
LCMXO3LF-1300E-5UWG36ITR	1300	1.2 V	5	Halogen-Free WLCSP	36	IND
LCMXO3LF-1300E-5UWG36ITR50	1300	1.2 V	5	Halogen-Free WLCSP	36	IND
LCMXO3LF-1300E-5UWG36ITR1K	1300	1.2 V	5	Halogen-Free WLCSP	36	IND
LCMXO3LF-1300E-5MG121C	1300	1.2 V	5	Halogen-Free csfBGA	121	COM
LCMXO3LF-1300E-6MG121C	1300	1.2 V	6	Halogen-Free csfBGA	121	COM
LCMXO3LF-1300E-5MG121I	1300	1.2 V	5	Halogen-Free csfBGA	121	IND
LCMXO3LF-1300E-6MG121I	1300	1.2 V	6	Halogen-Free csfBGA	121	IND
LCMXO3LF-1300E-5MG256C	1300	1.2 V	5	Halogen-Free csfBGA	256	COM
LCMXO3LF-1300E-6MG256C	1300	1.2 V	6	Halogen-Free csfBGA	256	COM
LCMXO3LF-1300E-5MG256I	1300	1.2 V	5	Halogen-Free csfBGA	256	IND
LCMXO3LF-1300E-6MG256I	1300	1.2 V	6	Halogen-Free csfBGA	256	IND
LCMXO3LF-1300C-5BG256C	1300	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	COM
LCMXO3LF-1300C-6BG256C	1300	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	COM
LCMXO3LF-1300C-5BG256I	1300	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	IND
LCMXO3LF-1300C-6BG256I	1300	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	IND

Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3LF-2100E-5UWG49CTR	2100	1.2 V	5	Halogen-Free WLCSP	49	COM
LCMXO3LF-2100E-5UWG49CTR50	2100	1.2 V	5	Halogen-Free WLCSP	49	COM
LCMXO3LF-2100E-5UWG49CTR1K	2100	1.2 V	5	Halogen-Free WLCSP	49	COM
LCMXO3LF-2100E-5UWG49ITR	2100	1.2 V	5	Halogen-Free WLCSP	49	IND
LCMXO3LF-2100E-5UWG49ITR50	2100	1.2 V	5	Halogen-Free WLCSP	49	IND
LCMXO3LF-2100E-5UWG49ITR1K	2100	1.2 V	5	Halogen-Free WLCSP	49	IND
LCMXO3LF-2100E-5MG121C	2100	1.2 V	5	Halogen-Free csfBGA	121	COM
LCMXO3LF-2100E-6MG121C	2100	1.2 V	6	Halogen-Free csfBGA	121	COM
LCMXO3LF-2100E-5MG121I	2100	1.2 V	5	Halogen-Free csfBGA	121	IND
LCMXO3LF-2100E-6MG121I	2100	1.2 V	6	Halogen-Free csfBGA	121	IND
LCMXO3LF-2100E-5MG256C	2100	1.2 V	5	Halogen-Free csfBGA	256	COM
LCMXO3LF-2100E-6MG256C	2100	1.2 V	6	Halogen-Free csfBGA	256	COM
LCMXO3LF-2100E-5MG256I	2100	1.2 V	5	Halogen-Free csfBGA	256	IND
LCMXO3LF-2100E-6MG256I	2100	1.2 V	6	Halogen-Free csfBGA	256	IND
LCMXO3LF-2100E-5MG324C	2100	1.2 V	5	Halogen-Free csfBGA	324	COM
LCMXO3LF-2100E-6MG324C	2100	1.2 V	6	Halogen-Free csfBGA	324	COM
LCMXO3LF-2100E-5MG324I	2100	1.2 V	5	Halogen-Free csfBGA	324	IND